

No.2406

DFB20T

Diffused Junction Type Silicon Diode

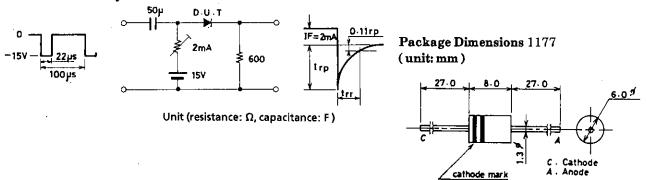
2.0A Power Rectifier

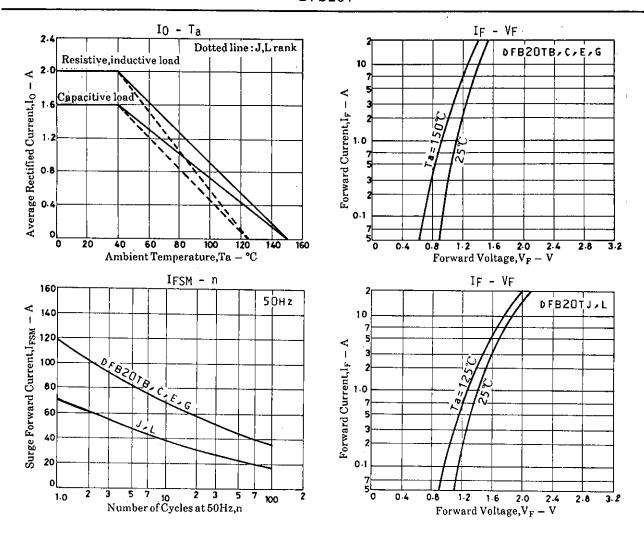
Features

- · High-speed switching use
- Reverse recovery time $trr = 0.15 \mu s \max (B,C,E,G)$ $trr = 0.3 \mu s \max (J,L)$
- \cdot Peak reverse voltage $V_{RM}\!=\!-100\,\text{to}\,-1000\text{V}$
- · Average rectified current IO=2.0A

| Absolute Maximum Ratings at Ta = 25°C | | | DFB20TB | DFB20TC | DFB20TE | DFB20TG | unit |
|--|--|--------------------------|---------------|---------------|---------------|------------|------|
| Peak Reverse Voltage | V_{RM} | | -100 | -200 | -400 | -600 | V |
| Average Rectified Current | $I_{\mathbf{O}}$ | $Ta = 40^{\circ}C$ | \rightarrow | \rightarrow | -→ | 2.0 | Α |
| Surge Forward Current | I _{FSM} | 50Hz sine wav 1 cycle | e, → | → | \rightarrow | 120 | A |
| Junction Temperature | Tj | | \rightarrow | → | \rightarrow | 150 | °C |
| Storage Temperature | Tstg | | \rightarrow | \rightarrow | | 40 to +150 | °C |
| | | DFB20TJ DFB20TL | | | | | unit |
| Peak Reverse Voltage | V_{RM} | | 800 | -1000 | | | V |
| Average Rectified Current | Io | $Ta = 40^{\circ}C$ | \rightarrow | 2.0 | | | Α |
| Surge Forward Current | I _{FSM} | 50Hz sine wav | e, → | 70 | | | Α |
| Junction Temperature | Тj | 1 cycle | > | 125 | | | °C |
| Storage Temperature | Tstg | -40 to +150 | | | | | °Č |
| Electrical Characteristics at Ta = 25°C | | | | | min | typ max | unit |
| Forward Voltage | $V_{\rm F}$ $I_{\rm F} = 2.0 \text{A (B,C,E,G)}$ | | | | 1.2 | V | |
| | | $I_F = 2.0 A (J,L)$ | · | | | 1.5 | V |
| Reverse Current | $I_{\mathbf{R}}$ | V_R : At each V_{RM} | | | • | -10 | μΑ |
| Reverse Recovery Time $trr I_F = 2mA, V_R = -15V(B,C,E,G)$ | | | | E,G) | | 0.15 | με |
| $I_F = 2mA, V_R = -15V (J, L)$ | | | | | | 0.3 | με |

Reverse Recovery Time Test Circuit





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